

**60V NPN LOW SATURATION POWER TRANSISTOR**
**Description**

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

**Features**

- $BV_{CEO} > 60V$
- $I_C = 3A$  High Continuous Collector Current
- $I_{CM}$  up to 6A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage  $V_{CE(SAT)} < 300mV @ 1A$
- Complementary PNP Type: DXT751Q
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

**Mechanical Data**

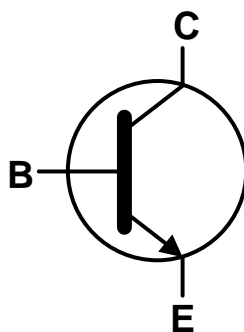
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.052 grams (Approximate)

**Applications**

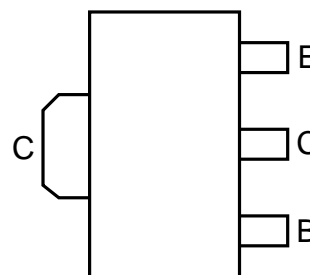
- Load Management Functions
- Motor Control
- DC-DC / DC-AC Converters



Top View



Device Symbol

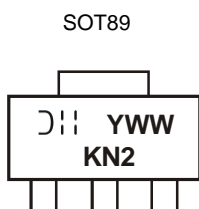


Top View Pinout

**Ordering Information** (Notes 4 and 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DXT651Q-13	Automotive	KN2	13	12	2,500

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to [http://www.diodes.com/product\\_compliance\\_definitions.html](http://www.diodes.com/product_compliance_definitions.html).
  5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


- KN2 = Product Type Marking Code  
 D = Manufacturer's Marking Code  
 YWW = Date Code Marking  
 Y = Last Digit of Year (ex: 6 = 2016)  
 WW = Week Code (01 to 53)

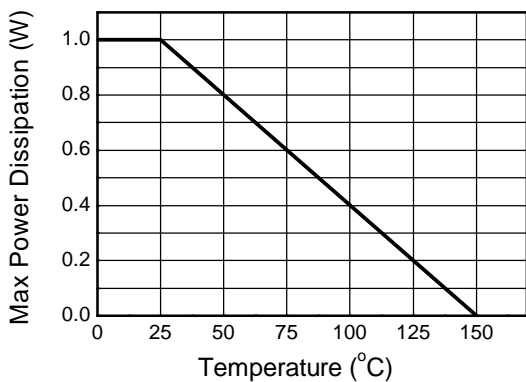
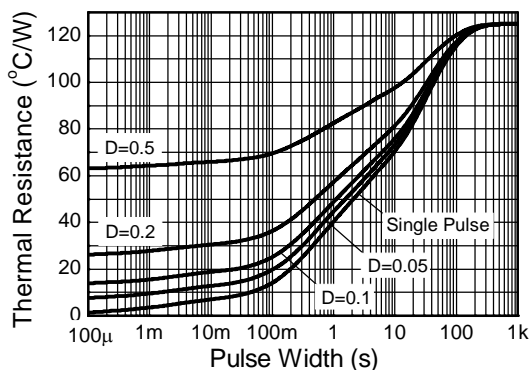
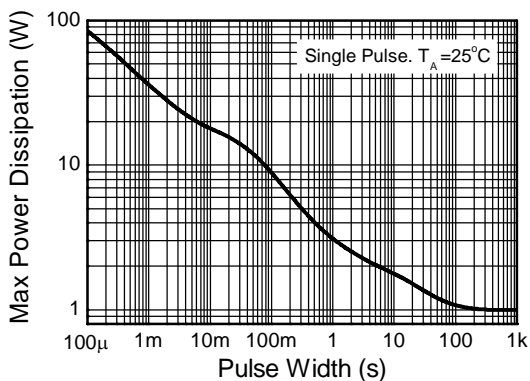
**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current	I <sub>C</sub>	3	A
Peak Pulse Collector Current	I <sub>CM</sub>	6	A
Peak Base Current	I <sub>B</sub>	500	mA

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	(Note 6)	1
		(Note 7)	2
Thermal Resistance, Junction to Ambient Air	R <sub>θJA</sub>	(Note 6)	125
		(Note 7)	62.5
Thermal Resistance, Junction to Leads	R <sub>θJL</sub>	6.0	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
- 6. For a device surface mounted on 15mm x 15mm x 0.6mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
  - 7. Same as note 6, except the device is mounted on 40mm x 40mm x 1.6mm FR-4 PCB.
  - 8. Thermal resistance from junction to solder-point (on the exposed collector pad).

**Thermal Characteristics and Derating Information**

**Derating Curve**

**Transient Thermal Impedance**

**Pulse Power Dissipation**

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions	
<b>OFF CHARACTERISTICS</b>							
Collector-Base Breakdown Voltage	$BV_{CBO}$	80	—	—	V	$I_C = 100\mu\text{A}$	
Collector-Emitter Breakdown Voltage (Note 9)	$BV_{CEO}$	60	—	—	V	$I_C = 10\text{mA}$	
Emitter-Base Breakdown Voltage	$BV_{EBO}$	5	—	—	V	$I_E = 100\mu\text{A}$	
Collector-Base Cutoff Current	$I_{CBO}$	—	—	0.1 10	$\mu\text{A}$	$V_{CB} = 60\text{V}$ $V_{CB} = 60\text{V}, T_A = +100^\circ\text{C}$	
Emitter-Base Cutoff Current	$I_{EBO}$	—	—	0.1	$\mu\text{A}$	$V_{EB} = 4\text{V}$	
<b>ON CHARACTERISTICS (Note 9)</b>							
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	0.08	0.3	V	$I_C = 1\text{A}, I_B = 100\text{mA}$	
			0.23	0.6	V	$I_C = 3\text{A}, I_B = 300\text{mA}$	
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	—	0.85	1.25	V	$I_C = 1\text{A}, I_B = 100\text{mA}$	
Base-Emitter Turn-On Voltage	$V_{BE(ON)}$	—	0.8	1	V	$V_{CE} = 2\text{V}, I_C = 1\text{A}$	
DC Current Gain	$h_{FE}$	70 100 80 40	200	—	—	—	$V_{CE} = 2\text{V}, I_C = 50\text{mA}$
			200	300			$V_{CE} = 2\text{V}, I_C = 500\text{mA}$
			185	—			$V_{CE} = 2\text{V}, I_C = 1\text{A}$
			120	—			$V_{CE} = 2\text{V}, I_C = 2\text{A}$
<b>SMALL-SIGNAL CHARACTERISTICS</b>							
Transition Frequency	$f_T$	140	200	—	MHz	$V_{CE} = 5\text{V}, I_C = 100\text{mA}, f = 100\text{MHz}$	
Output Capacitance	$C_{obo}$	—	—	30	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$	
Switching Times	$t_{ON}$	—	35	—	ns	$V_{CC} = 10\text{V}, I_C = 500\text{mA}, I_{B1} = -I_{B2} = 50\text{mA}$	
	$t_{OFF}$	—	230	—	ns		

Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

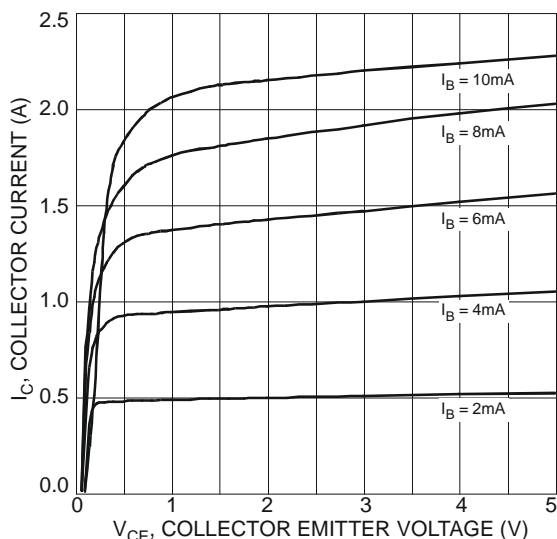


Figure 1 Typical Collector Current vs. Collector-Emitter Voltage

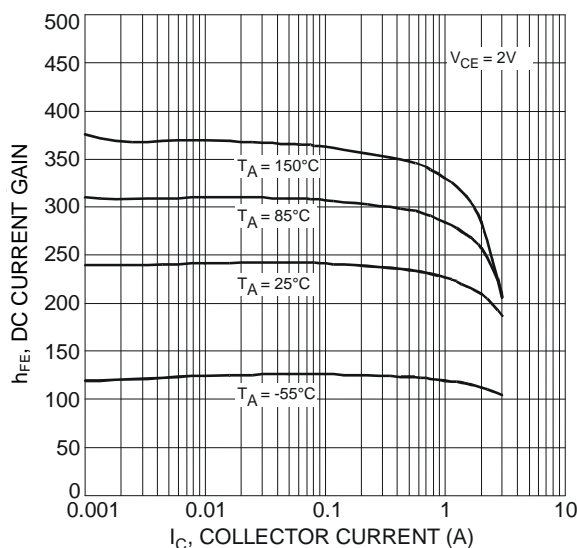


Figure 2 Typical DC Current Gain vs. Collector Current

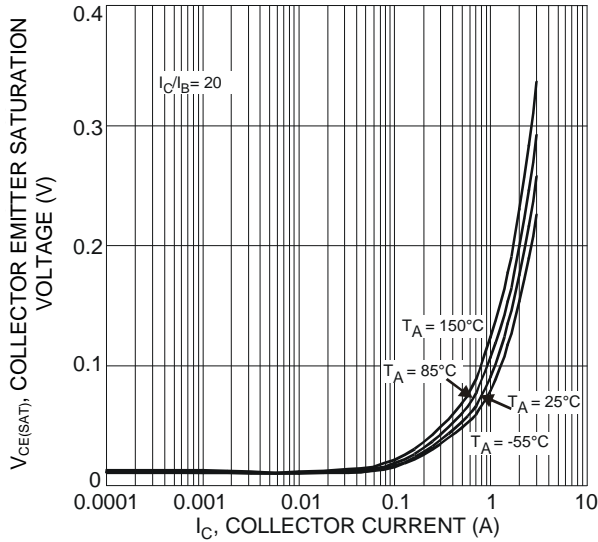


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

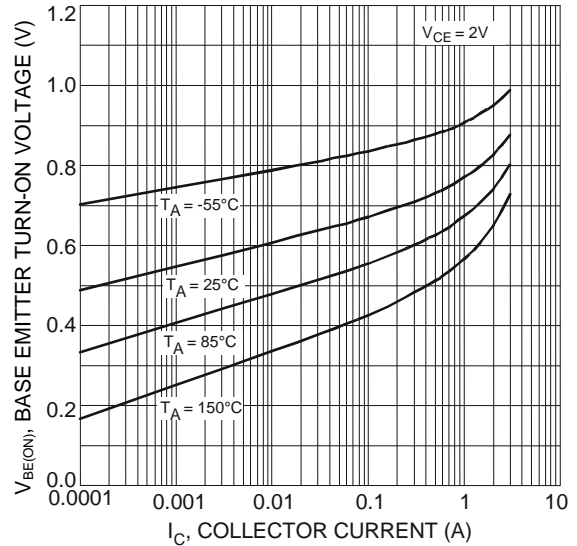


Figure 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

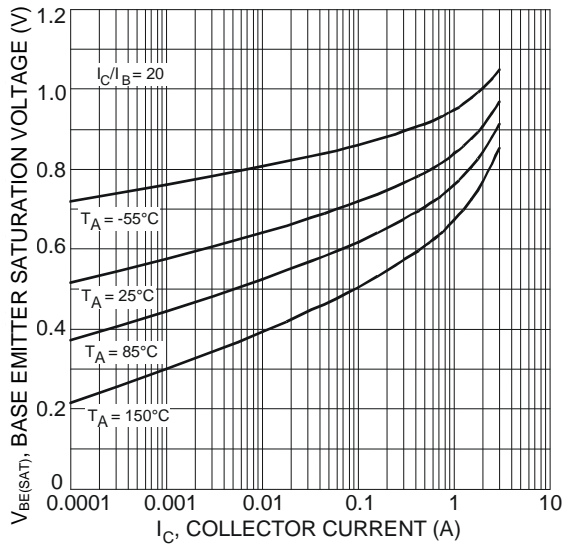


Figure 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

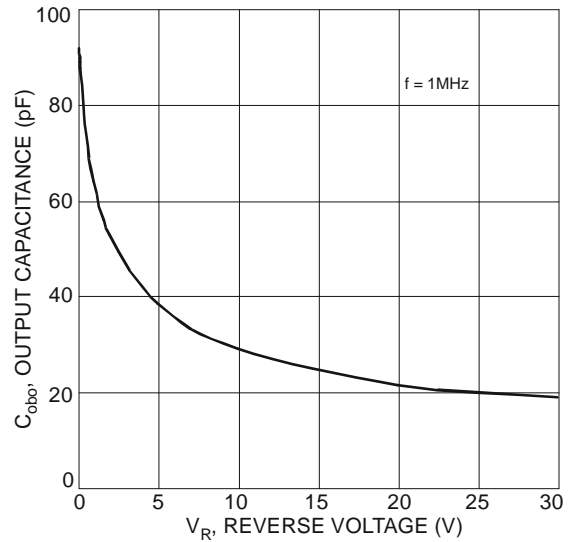


Figure 6 Typical Output Capacitance Characteristics

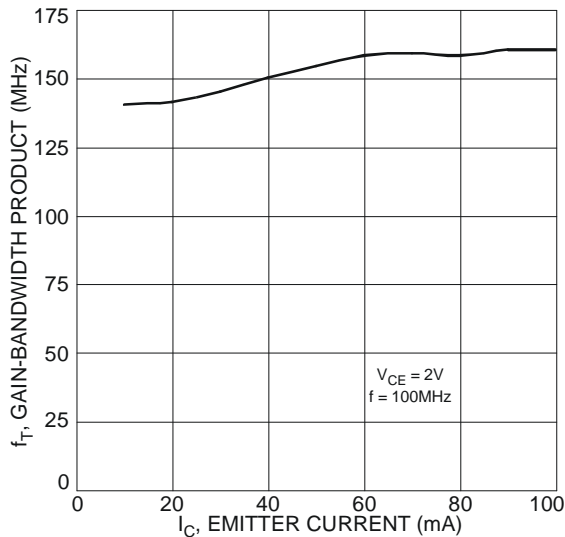
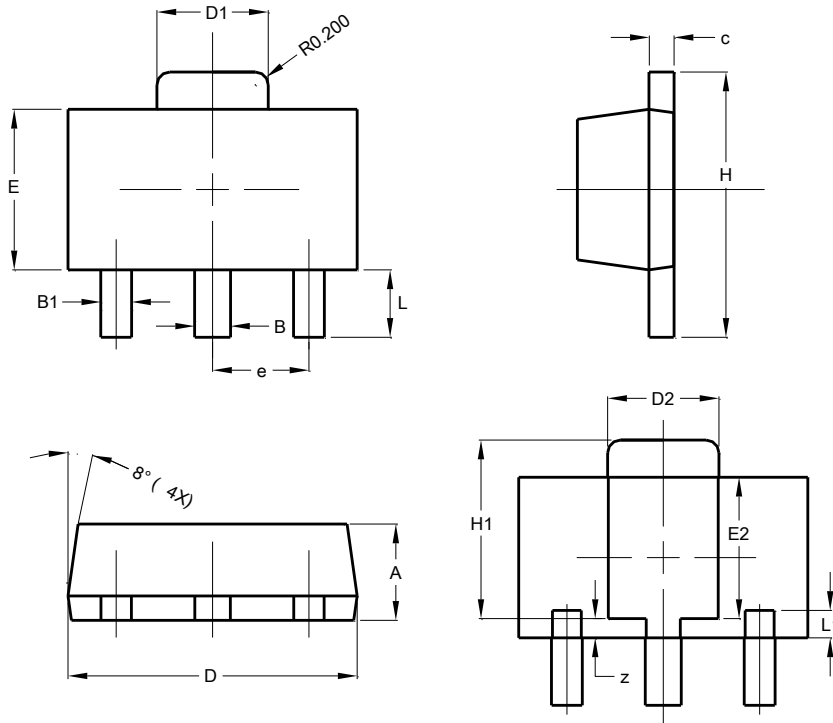


Figure 7 Typical Gain-Bandwidth Product vs. Emitter Current

**Package Outline Dimensions**

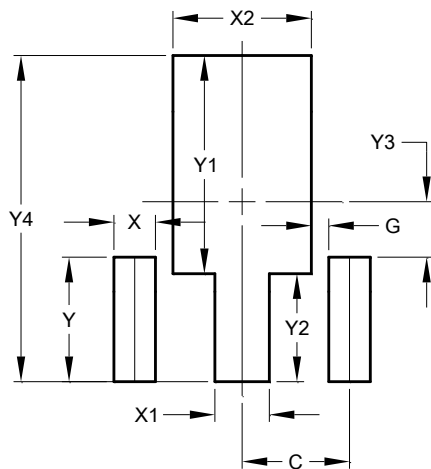
Please see <http://www.diodes.com/package-outlines.html> for the latest version.



SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
<b>All Dimensions in mm</b>			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

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- Техническая поддержка проекта;
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